

# Hard superconducting nitrides

Xiao-Jia Chen\*, Viktor V. Struzhkin\*, Zhigang Wu\*, Maddury Somayazulu†, Jiang Qian‡, Simon Kung\*§, Axel Nørlund Christensen¶, Yusheng Zhao‡, Ronald E. Cohen\*, Ho-kwang Mao\*, and Russell J. Hemley\*||

\*Geophysical Laboratory, Carnegie Institution of Washington, Washington, DC 20015; †Advanced Photon Source, Argonne National Laboratory, Argonne, IL 60439; ‡Los Alamos Neutron Science Center Division, Los Alamos National Laboratory, Los Alamos, NM 87545; §Department of Chemistry, California Institute of Technology, MSC 593, Pasadena, CA 91126; and ¶Højskolvej 7, DK-8210 Aarhus V, Denmark

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**Detailed study of the equation of state, elasticity, and hardness of selected superconducting transition-metal nitrides reveals interesting correlations among their physical properties. Both the bulk modulus and Vickers hardness are found to decrease with increasing zero-pressure volume in NbN, HfN, and ZrN. The computed elastic constants from first principles satisfy  $c_{11} > c_{12} > c_{44}$  for NbN, but  $c_{11} > c_{44} > c_{12}$  for HfN and ZrN, which are in good agreement with the neutron scattering data. The cubic  $\delta$ -NbN superconducting phase possesses a bulk modulus of 348 GPa, comparable to that of cubic boron nitride, and a Vickers hardness of 20 GPa, which is close to sapphire. Theoretical calculations for NbN show that all elastic moduli increase monotonically with increasing pressure. These results suggest technological applications of such materials in extreme environments.**

elasticity | elastic constants | equations of state | hardness | binary compounds

**H**ard superconducting materials are of considerable interest for specific electronic applications. Superconductivity has been discovered in diamond, generally believed to be the hardest material having very high shear and bulk moduli (1, 2), with a superconducting transition temperature ( $T_c$ ) near 4 K when doped with boron (3). However, the transition-metal compounds having the sodium chloride (B1) structure (e.g., NbN, NbC, ZrN, or HfN) are also hard superconductors but with relatively higher  $T_c$ s. The transition temperatures of solid solutions of NbN and NbC can reach a maximum value of 17.8 K, which is close to those found for the cubic A15-type compounds such as Nb<sub>3</sub>Sn and V<sub>3</sub>Si (4). The refractory characteristics of these transition-metal nitrides and carbides have been applied as coatings to increase the wear resistance, for instance, in cutting tools as well as for magnetic storage devices. The unusual hardness enhancement in these materials has been theoretically shown to originate from a particular  $\sigma$ -band of bonding states between the non-metal  $p$  orbitals and the metal  $d$  orbitals that strongly resists shearing strains (5). At the moment, there is a need to investigate elastic and mechanical properties of these superconductors under simulated extreme working conditions.

Here, we report both experimental and theoretical studies of the equation of state, elasticity, and hardness of selected superconducting transition-metal nitrides. We find that the cubic  $\delta$ -NbN superconducting phase possesses a bulk modulus of 348 GPa, comparable to that of cubic boron nitride, and a Vickers hardness of 20 GPa, which is close to sapphire (Al<sub>2</sub>O<sub>3</sub>) (6). The results indicate that these nitrides are good candidates for engineering hard superconducting materials.

## Experimental and Theoretical Details

Equations of state studies were based on angle-dispersive synchrotron powder x-ray diffractometry with a diamond anvil cell. The diffraction experiments were carried out at the synchrotron beam line 16ID-B of the Advanced Photon Source High Pressure Collaborative Access Team. A 500 × 500- $\mu$ m<sup>2</sup> monochromatic beam of wavelength  $\lambda = 0.4219$  Å was focused by using a pair of bimorph mirrors to a 10 × 12- $\mu$ m<sup>2</sup> beam. The diffraction data were recorded on a MAR345 imaging plate and integrated by using FIT2D software

(7). The geometric parameters and the wavelength were calibrated by using a silicon standard (NIST 640c standard). Powder samples were loaded into a hole in stainless-steel gaskets with a nominal diameter of 100  $\mu$ m and 10- to 15- $\mu$ m thickness between two 400- $\mu$ m-diameter flat diamond culets. A ruby chip served as an optical pressure sensor in the diamond anvil cell (8). LiF was chosen as a pressure medium for NbN, and silicon oil was used as a pressure medium in the HfN and ZrN samples. The powder samples with grain sizes <2  $\mu$ m were obtained by crushing the single crystals of NbN, HfN, and ZrN. Single crystals grown by the zone-annealing technique have been detailed (9–11). Hardness measurements were performed on the nitride single crystals by means of a Vickers indentation method with a pyramidal diamond indenter.

The thermodynamical stability of these transition-metal nitrides are examined by first-principles calculations. All calculations are based on the density functional theory within the local density approximation. We used a plane-wave basis and pseudopotentials with the ABINIT (version 4.3.2) package (12) to optimize structures and calculate total energies and electronic structures. The OPIUM program (13) was used to generate pseudopotentials for N, Nb, Zr, and Hf. Plane-wave basis sets with a cut-off of 50 Ha were tested and found to be highly converged. A dense 16 × 16 × 16  $k$ -point mesh was used over the Brillouin zone.

The elastic moduli of these transition-metal nitrides were calculated from stress ( $\sigma$ ) changes caused by very small strain ( $\varepsilon$ ) through the relation  $c_{ij} = \sigma_i/\varepsilon_j$  (14). Cubic crystals have only three independent elastic constants, namely  $c_{11}$ ,  $c_{12}$ , and  $c_{44}$ , for the B1 structure. The bulk modulus  $K_0$  was calculated from fitting energy and volume data to the Vinet equation of state (15).

## Results and Discussion

X-ray diffraction patterns of NbN were taken up to 51.2 GPa. Typical patterns taken in the course of increasing pressure are shown in Fig. 1. The ambient pressure phase for NbN is *fcc*, as evidenced by the observations of (111), (200), (220), (311), and (222) peaks, and the measured lattice parameter is  $a_0 = 4.379(2)$  Å. The (111) peak of LiF shifts much faster than the (200) peak of NbN under pressure, almost overlapping at 30 GPa but separating again at 51.2 GPa. At high pressures, the same diffraction peaks still remain, indicating that there is no phase transformation up to 51.2 GPa. The measured lattice parameter at 51.2 GPa is 4.213(3) Å, which corresponds to a volume compression  $V/V_0$  of 0.89.

Fig. 2 shows the measured pressure-volume curve or equation of state for NbN, HfN, and ZrN samples to 51.2 GPa at room temperature. The experimental data were fitted to the Vinet equation of state (16)

$$P = \frac{3K_0(1-x)}{x^2} \exp \left[ \frac{3}{2} (K'_0 - 1)(1-x) \right], \quad [1]$$

with  $x = (V/V_0)^{1/3}$ , where  $V_0$  and  $V$  are the zero-pressure and compressed volumes and  $K_0$  and  $K'_0$  represent the bulk modulus at

||To whom correspondence should be addressed. E-mail: r.hemley@gl.ciw.edu.

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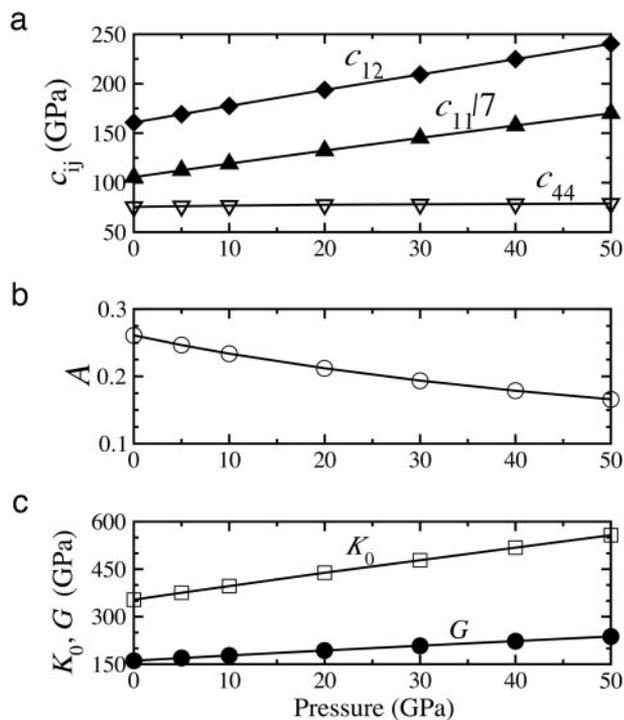


Fig. 3. Pressure dependence of the elastic constants  $c_{ij}$  (a), the elastic anisotropy  $A$  (b), and the bulk modulus  $K_0$  and shear modulus  $G$  (c) in cubic  $\delta$ -NbN.

note that the inequality  $c_{11} > c_{12} > c_{44}$  is satisfied over a wide pressure range (i.e., to 50 GPa).

The elastic anisotropy at high pressure is important for understanding the evolution of bonding in the system. A measure of the anisotropy of the elasticity is  $A = 2c_{44}/(c_{11} - c_{12})$  for cubic crystals. For isotropic elasticity, the two shear moduli  $(c_{11} - c_{12})/2$  and  $c_{44}$  are equal and the anisotropy becomes unity. In Fig. 3b we plotted the pressure dependence of  $A$  for cubic  $\delta$ -NbN.  $A$  shows a gradual decrease with increasing pressure. The rapid increase of  $c_{11}$  with pressure is expected because of enhanced nearest-neighbor interaction, which leads to a stretching of the metal-N bonds ( $c_{11} - c_{12}$ ). On the other hand, pressure induces  $sp \rightarrow d$  electron transfer from N to Nb atoms (22), giving rise to the occupation of  $\sigma$ -bonding states derived from  $d-d$  interactions. This band is lowered under shear strain (5), which gives a modest negative contribution to  $c_{44}$ . As a result, the pressure-induced decrease of  $A$  is dominated by stretching of the metal-N bonds rather than the gradual shearing of the structure.

Aggregate values for the bulk  $K_0$  and shear  $G$  modulus were obtained from the individual elastic constants (Fig. 3c). The bulk modulus increases with pressure and reaches 557 GPa at pressure of 50 GPa. At 20 GPa, the bulk modulus of  $\delta$ -NbN reaches the zero-pressure value of the bulk modulus of diamond (1). The shear modulus also increases across the whole pressure range. The behavior of the moduli suggests an increasing hardness in this material with pressure.

Using conventional microhardness testing techniques, the Vickers hardness  $H_V$  was measured under a loading force from 0.49 to 9.8 N. The loading time was fixed at 15 s. Fig. 4 shows the measured  $H_V$  for the studied transition-metal nitrides under various loads. From the results, it can be seen that the hardness decreases with increasing lattice parameter. The average hardness values are 20.0, 19.5, and 17.4 GPa under a load of 0.49 N for NbN, HfN, and ZrN, respectively. For

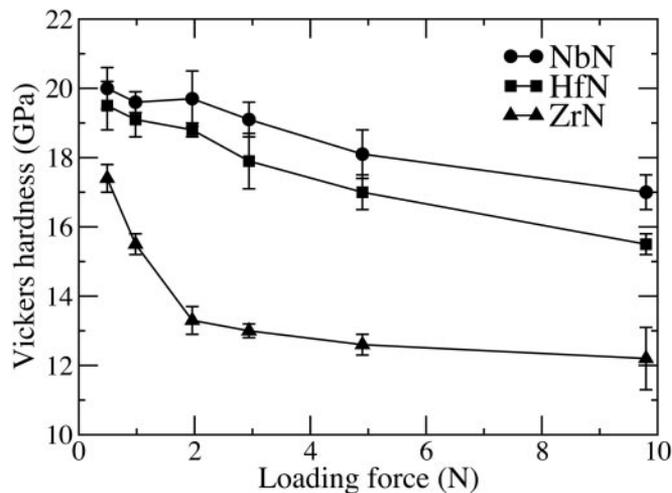


Fig. 4. Vickers hardness of the transition-metal nitrides NbN, HfN, and ZrN single crystals as a function of the loading force.

comparison, our measured  $H_V$  of 20 GPa for cubic  $\delta$ -NbN is slightly lower than the reported  $\approx 23$  GPa in a  $\delta$ -NbN<sub>0.93</sub> film (23). The measured  $H_V$  of 15.5 GPa in HfN under a loading force of 9.8 N is very close to the reported  $H_V^{10N}$  of 14.5 GPa in HfN ceramics (24). Another observation of our results is that the Vickers hardness decreases with the increase in load. Similar behavior has been reported for cubic boron nitride and Al<sub>2</sub>O<sub>3</sub> (25). Note that the cubic  $\delta$ -NbN superconducting phase has a the bulk modulus of 348 GPa, comparable to that of cubic boron nitride, and a Vickers hardness of 20 GPa, the same as sapphire. Recent studies in films (23) revealed that the hardness of the hexagonal  $\delta'$ -NbN phase with high nitrogen concentration can reach to 40 GPa. The relatively large bulk modulus and high hardness in the superconducting cubic  $\delta$ -NbN phase are favorable for potential hard-device applications.

NbN has the highest  $T_c$  among the transition-metal nitrides. Currently, NbN films are being examined in applications of radio frequency superconducting accelerator cavities (26), superconducting quantum interference devices (27), superconducting hot-electron photodetectors (28), and IR sensors (29). Our results reveal that this material is highly incompressible compared with HfN and ZrN because of its high values of the bulk modulus and Vickers hardness. Application of pressure increases both the bulk and shear moduli. The enhancement of hardness is therefore expected under high pressure. Meanwhile,  $T_c$  was found to increase with pressure in this compound (30). These combined features make NbN a good candidate along with hard superconductors, such as boron-doped diamond, for possible applications under extreme conditions.

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